# Coplanar Micro-Strips/Electrospun sensor system to Measure the Electronics Properties of the Polyethylene Oxide (PEO) Electrospun

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Abstract— In the literature we found different kind of film conducting polymers, as Polyaniline (PANI) or Polypyrrole (PPY), used as sensor element integrated in a Field Effect Transistor (FET) for the detection of gas or photogenes. In this work we proposed a sensor system prototype based on the combination of a coplanar micro strip (CPµS) waveguide and polymer nanofibers met (electrospun) called, CPµS/PNW sensor system, for target element (bio element or gas) detection. The detection idea is based on the impedance change measurement in the frequency range. The first step toward to develop the sensor is to investigate and understand the low frequency (0.1 to 1 MHz) electrodynamics response properties of the CPuS waveguide with (CPuS/PNW) and without nanofibers. We develop a transmission line mathematical model to describe the CPµS/PNW sensor system, the mathematical model was simulated with Scilab and the results were compared with the CPµS/PNW experimental data to see the degree of agreement between model and experiment. The impedance curves obtained from the experimental data show a good agreement with the model, which predict  $CP\mu S/PNW$  ( $CP\mu S +$  electrospun) impedance curve lower than the CPµS impedance curve. The electronics property (impedance) of the PEO electrospun was calculated from the difference between both impedance curves, this difference represent the polymer nanofibers mat impedance. The curves exhibited approximately a sub-linear power law decrease with frequency, which is consistent with the behavior found in polymers. The polymer nanofibers mat was produced by electrospinning method, where the diameter of the nanofibers obtained are in the range of 100 nm and 900 nm.

Keywords—coplanar µ-Strip; transmission line; impedance spectrsocopy; polymer electrospun; electrospinning

## I. INTRODUCTION

In the literature we found research focusing in the investigation of the low and high frequency properties of conducting film polymer for gas and bio sensors applications [1, 2, 3]. In [4] it is reported of a transistor field effect (FET) as sensor based on silicon nanowire (SNW), here the nanowire (NW) is the sensor element where the NW is the gate of the FET and this amplifies the conductance change in the NW when the target is attached nanowire surface, this is basically the detection method using the FET as an amplifier, [5]. The sensitivity of the DC electrical properties of silicon nanowire to molecules adsorbed (Biosensor) on their surfaces, shown by [4], also raises the question of whether similar AC conductance changes (or another similar method) exist and can be exploited using instead silicon NW a conductive or non conductive polymer NW (nanofibers) for Biosensor purposes [5, 6, 7]. As the first goal we present sensor prototype for the measurement of the electrical properties of polyethylene oxide (PEO) electrospun (non conductive polymer nanofibers net), which was possible using the combination of the coplanar micro strip (CPuS) waveguide with the PEO electrospun as an all system. We called this system as the "CPµS/PNW sensor system". We investigate the electrodynamics response properties of PEO electrospun for the low frequency of [0.1–1MHz]. For the "CPµS/PNW sensor system" we developed a mathematical model based on the transmission line theory where the nanofibers electrospun impedance is modeled by a conductance and capacitance in parallel with the transmission line model of the sensor system, Fig. 1 and 2. The model was simulated with the software Scilab and the simulation results were compared with the experimental data of the CPµS to see the agreement of the model, Fig. 4. To measure the PEO electrospun impedance, first the impedance characteristic of the CPuS without electrospun is measured and then the impedance characteristic of the CPµS/PNW system was measured, where the electrospun was deposited by electrospinning on the surface of the CPµS. From the measurements (experimental data) we obtained two curves, one for the CPuS without electrospun and one for the CPµS/ PNW system, Fig. 10, using the difference between curves we calculate the impedance difference ( $\Delta Z$ ), equivalent to the PEO electrospun impedance. Furthermore the impedance vs. frequency curve exhibited approximately a sublinear power law decrease with frequency which is consistent with the behavior founded in disordered system as polymer [9]. In the literature we found many research on polymer film DC electrical properties, but a few research about its frequency properties, and a few published papers about the electrical properties of polymer electropsun. One reason for this is due the large impedance of the polymer compare with semiconductor and because of the individual polymer nanowire, the component of the electrospun, which have typically high impedance in the order of 10 M $\Omega$  or even more. Compared this high impedance to the 50  $\Omega$  impedance of all microwave test equipment and the 377  $\Omega$  impedance of free space, and if we take into account that the interaction between the nanowire net and the electromagnetic field is very small (signal below instrumental background), we see that the measurement of the electrospun impedance is a difficult task. To overcome this limitation we have develop the CPuS/PNW system to measure the electrospun impedance. This allowed us to accurately extract the impedance value for the PEO electrospun, and is also possible to extract the conductance and the capacitance. The nanofibers net or electrospun is produced by electrospinning method [8], which is a cost-effective and versatile process to fabricate nanofibers from a wide range of materials at room temperature and atmospheric pressure, of which the diameter ranges from tens of nanometers to a few micrometers, Fig. 5 and 7. The paper is organized as follow: (I) present the introduction, (II-A) the transmission line model for the CP $\mu$ S, (II-B) the simulation of the CP $\mu$ S, (III-A) the electrospinning method, (III-B) the impedance measurement and equipment, (IV) the results and (V) the conclusion.

#### II. COPLANAR MICRO STRIP MODEL

## A. CPµS mathematical model based on transmission line.

Equations (1) show the total model for the impedance output of the CP $\mu$ S. We assume an open line, therefore the load impedance ( $Z_L$ ) goes to infinity and the total impedance model is reduced to (2). The impedance model is composed by the characteristic impedance  $Z_0$  (3) and the propagation constant  $\gamma$  (4) which are composed by R, L, C and G. The capacitance is described by (5) and (6) where  $C_a$  is the air capacitance and  $C_{su}$ the substrate capacitance. The conductance is described by (7) and the total resistance by (10). The Fig. 1 show the transmission line model for the distributed element R, L, C and G, which are distributed along the CP $\mu$ S.

## *1) Total impedance*

$$Z_t = Z_0 \cdot \frac{Z_L + Z_0 \tanh \gamma l}{Z_0 + Z_L \tanh \gamma l}$$
(1)

At the end of the CPµS the line is open, therefore we have:

$$Z_L \to \infty \implies Z_t = \frac{Z_0}{\tanh \gamma l}$$
 (2)

where:

$$Z_0 = \sqrt{\frac{R + j\omega L}{G + j\omega C}}$$
(3)  
$$\gamma = \sqrt{(R + j\omega L)(G + j\omega C)}$$
(4)

 $Z_0$ : Characteristic impedance of the sensor (CP $\mu$ S)  $\gamma$ : Propagation constant of the sensor (CP $\mu$ S)

## 2) Capacitance

$$C_{total} = C_a + C_{su} \tag{5}$$

$$C_{total} = \varepsilon_0 \frac{(\varepsilon_a + \varepsilon_{su})}{2} \cdot \frac{k \left[ \left( 1 - \left( \frac{a}{a+2w} \right)^2 \right)^{1/2} \right]}{k \left[ \frac{a}{a+2w} \right]}$$
(6)

where:

k[x]: Complete elliptic integral of the first order  $\varepsilon_a$ : Air dielectric constant  $\varepsilon_{su}$ : Substrate dielectric constant  $\varepsilon_0$ : Electric permittivity of free space  $C_a$ : Air capacitance  $C_{su}$ : Substrate capacitance  $C_{total}$ : Total capacitance *w*: strip width and *a*: distance between strips, Fig. 3

3) Conductance

$$G_{s} = \frac{\sqrt{\varepsilon_{eff_{1}}}}{120\pi} \frac{k \left[\frac{a}{a+w}\right]}{k \left[\left(1 - \left(\frac{a}{a+w}\right)^{2}\right)^{1/2}\right]}$$
(7)

where:

 $\varepsilon_{effl}$ : effective dielectric of the CP $\mu$ S

4) Inductance

$$L = \mu_0 \varepsilon_0 \frac{1}{C_a} \tag{8}$$

where:

 $\mu_0$ : Magnetic permeability of free space.

 $C_a$ : Total capacitances calculate by (6) when al dielectric materials are assumed to be replacing by air.

## 5) Resistance

$$R_{total} = R_1 + R_2 \tag{9}$$

where:

R<sub>total</sub>: Total resistance; R<sub>1</sub>: strip1 resistance; R<sub>2</sub>: Strip2 resistance.

$$R_{1} = R_{2} = R = R_{DC} + \frac{\sqrt{\rho \mu \pi f}}{w}$$
$$R = \frac{\rho}{w h} + \frac{\rho}{w \delta_{skin}} ; \quad R_{DC} = \frac{\rho}{w h}$$
$$\implies R = R_{DC} \left( 1 + h \sqrt{\frac{\mu \pi f}{\rho}} \right)$$

then the total resistance is:

$$R_{total} = 2R = 2R_{DC} \left( 1 + h \sqrt{\frac{\mu \pi f}{\rho}} \right)$$
(10)

where:

 $\begin{array}{l} \rho : \mbox{Strip resistivity; w: strip width; h: strip high} \\ \mu : \mbox{Strip permeability; } \mu = \mu_0 \ \mu_r \\ \mu_0 : \mbox{Free space magnetic permeability} \\ \mu_r : \mbox{Relative permeability} \\ \delta_{skin} : \mbox{Skin effect} \end{array}$ 

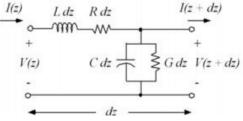


Fig. 1. Transmission line model for the CP $\mu$ S. Where *L*, *R*, *C* and *G* are element distributed through the line.

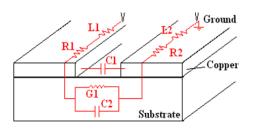
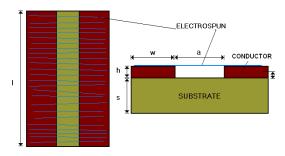
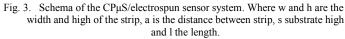


Fig. 2. Schema of the  $CP\mu S$  with its equivalent distribution circuit model.





## B. Simulations of the CPµS impedance

The sensor system model described in II was programmed and simulated using the open source software Scilab (www.scilab.org). From the simulation we obtained the total impedance vs. frequency curve for the CP $\mu$ S defined by (1). The frequency simulation was in the low frequency (0.1 to 1MHz) range. The Fig. 4 show the simulation results for the CP $\mu$ S in the frequency range [0.6–1.0 MHz]. For the simulation in Scilab we used the size parameters and the physical constant showed in the Table. 1. The size parameters were measured by the CLSM in the 3D mode, Fig. 6. And the Fig. 7 shows the fiber's diameter distribution measured by CLSM in 2D mode.

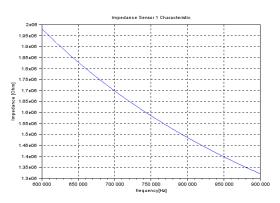


Fig. 4. Simulation curve of Impedance vs. frequency for the CPµS, sensor 1.

 
 TABLE I.
 VALUE OF THE DIMENSIONS OF THE SENSOR S1 BY CLSM AND THE PHYSICAL CONSTANT USED TO CALCULTE THE IMPEDANCE.

Size Parameter	Value [mm]	Physical Constant	Value
S	1,6	ε <sub>0</sub>	8,85·10 <sup>-12</sup> [F/m]
h	0,144	ε <sub>a</sub>	1,00058986
W	0,54	$\mu_0$	4π·10 <sup>-7</sup> [H/m]
а	2,02	$\rho_{Al}$	1,72·10 <sup>-8</sup> [Ωm]
1	13000		

#### III. EXPERIMENT AND EQUIPMENT

## A. Electrospining Process

The nanofiber is produced by electrospinning method, which is a cost-effective and versatile process to fabricate nanofibers from a wide range of materials at room temperature and atmospheric pressure, of which the diameter ranges from tens of nanometers to a few micrometers. We called electrospun the net of fibers collected during the electrospinning process, Fig. 5. The equipment is composed by a Harvard syringe pump, high voltage device and two metal electrodes in a vertical orientation, the electrode at the bottom is the collector. The solution used for the electrospinning is composed by 4% PEO (900000 Mw) and 96 % distilled-water (solvent).

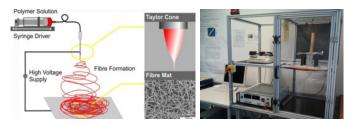


Fig. 5. Electrospinning process schema and Lab-Equipment.

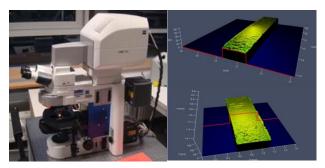


Fig. 6. Confocal Laser Scaning Microscope (CLSM, C. Zeiss) and the 3D image of the strips of the CPµS.

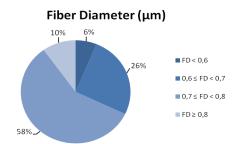


Fig. 7. Circle diagram of the PEO fiber's diameter distribution.

## B. Impedenace measurement

The impedance vs. frequency of the sensor system with and without PEO electrospun was measured by the HIOKI 3552 LCR spectrometer under ambient condition, T=20.3°C (temperature); Hr=36% (relative Humidity), Fig. 8.

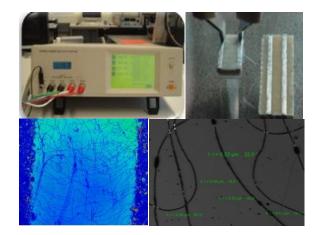


Fig. 8. Up, Hioki LCR device and image of the CPµS/electrospun sensor system S1 and S3 (thin strip and FR2 substrate). Down, CLSM 2D image of the sensor system/electrospun nanofibers (Ag strips and glass substrate) and PEO nanofibers with its diameter measured by ZEN (C. Zeiss Software).

## IV. RESULTS

Two curves were obtained from the experimental data, through the measurement of the impedance spectroscopy of the CPuS/electrospun sensor system without and with electrospun using the Hioki LCR instrument, Fig. 9. The Scilab simulation results are in agreement with the experimental results, which mean, that we have develop a good mathematical and physical model to describe the sensor system, Fig. 2 and 3. Using the difference between both curves we can see that is possible to measure the impedance, conductance and the capacitance of the PEO electrospun. We have found that the complex AC impedance of the polymer electrospun exhibited approximately a sub-linear power law decrease with frequency that is consistent with behavior found in polymer (insulator), Fig. 9. The Fig. 4 shows the simulation curve by Scilab for the CPµS sensor 1 without electrospun. These curves show a similar behavior as the experimental curve.

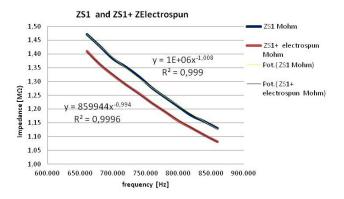


Fig. 9. Experimental and fit curve with its power law function for CPμS/electrospun sensor system S1. The blue line is CPμS without electrospun and the red line is the CPμS with PEO naofibers electropsun.

#### V. CONCLUSONS

We have found the problem due to the small interaction between the nanofibers and the electromagnetic field (which produces a signal below the instrumental background) was overcome through the CP $\mu$ S/electrospun system. Therefore CP $\mu$ S/electrospun system is a good approach to measure the electrodynamics response of the electrospun PEO nanofibers, which means that we can measured the impedance change even if we used non conductive polymer as the PEO. From the obtained curves we can calculate the electronics properties, (impedance, conductance and capacitance) of the PEO nanofibers electrospun. Furthermore the curves show a sub-linear power law which is consistent with the behavior found in polymers and the simulation shows a good agreement with the experiments.

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